Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 16 A



- Ultrafast recoveryUltrasoft recovery
- Very low I_{RRM}
- Very low I_{RR}
- Very low Q_{rr}
- Specified at operating conditions
- Lead (Pb)-free
- Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

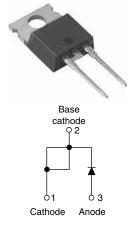
HFA16TB120 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 16 A continuous current, the HFA16TB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA16TB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		1200	V	
Maximum continuous forward current	I _F	T _C = 100 °C	16		
Single pulse forward current	I _{FSM}		190	А	
Maximum repetitive forward current	I _{FRM}		64		
Maximum navver dissinction	PD	T _C = 25 °C	151	W	
Maximum power dissipation		T _C = 100 °C	60	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

* Pb containing terminations are not RoHS compliant, exemptions may apply







TO-220AC

PRODUCT SUMMARY				
V _R	1200 V			
V _F at 16 A at 25 °C	3.0 V			
I _{F(AV)}	16 A			
t _{rr} (typical)	30 ns			
T _J (maximum)	150 °C			
Q _{rr} (typical)	260 nC			
dl _{(rec)M} /dt (typical) at 125 °C	76 A/µs			
I _{RRM} (typical)	5.8 A			

HFA16TB120PbF



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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		1200	-	-	
Maximum forward voltage V _{FM}		I _F = 16 A	See fig. 1	-	2.5	3.0	V
	V _{FM}	I _F = 32 A		-	3.2	3.93	
	I _F = 16 A, T _J = 125 °C	1	-	2.3	2.7		
Maximum reverse		$V_{R} = V_{R}$ rated	0	-	0.75	20	
leakage current	I _{RM}	T_J = 125 °C, V_R = 0.8 x V_R rated	See fig. 2	-	375	2000	μΑ
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	27	40	pF
Series inductance	LS	Measured lead to lead 5 mm from package body - 8.0 -		nH			

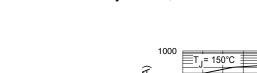
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
.	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	30	-	
Reverse recovery time See fig. 5 and 10	t _{rr1}	T _J = 25 °C	I _F = 16 A	-	90	135	ns
	t _{rr2}	T _J = 125 °C		-	164	245	
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	5.8	10	A
See fig. 6	I _{RRM2}	T _J = 125 °C		-	8.3	15	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C	dl _F /dt = 200 A/μs	-	260	675	nC
See fig. 7	Q _{rr2}	T _J = 125 °C	V _R = 200 V	-	680	1838	
Peak rate of fall of recovery current during t _h	dl _{(rec)M} /dt1	T _J = 25 °C	-	-	120	-	A/µs
See fig. 8	dl _{(rec)M} /dt2	$T_J = 125 \ ^\circ C$		-	76	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	Tlead	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	0.83	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.50	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)
Marking device		Case style TO-220AC		HFA16	TB120	



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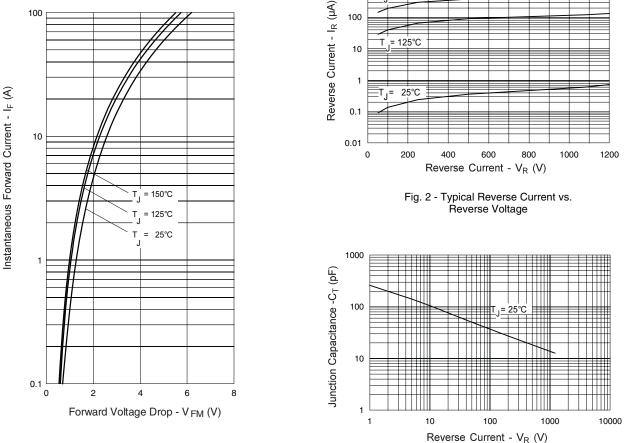
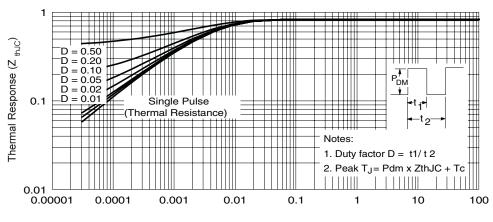


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



t₁, Rectangular Pulse Duration (sec)

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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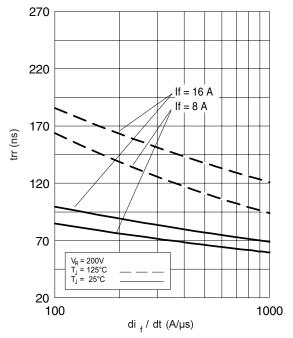


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt (Per Leg)

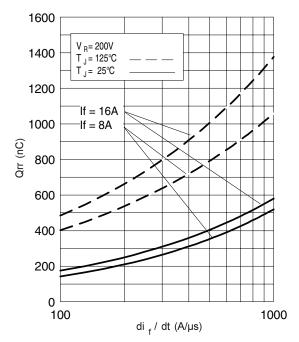


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

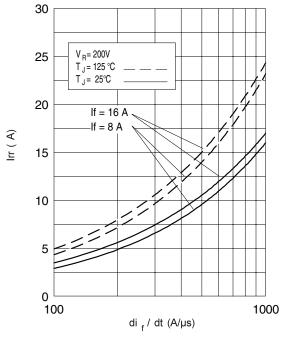


Fig. 6 - Typical Recovery Current vs. di_F/dt (Per Leg)

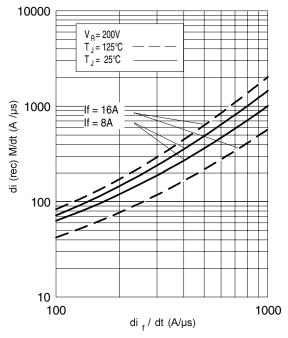


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt (Per Leg)





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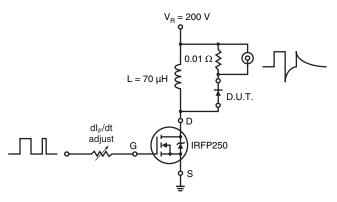


Fig. 9 - Reverse Recovery Parameter Test Circuit

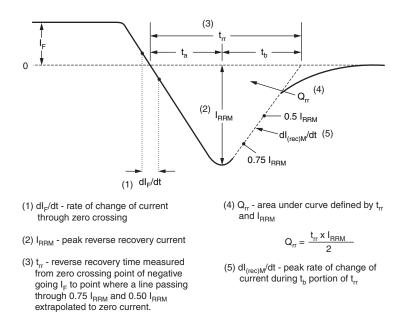


Fig. 10 - Reverse Recovery Waveform and Definitions

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95221				
Part marking information	http://www.vishay.com/doc?95224			



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